

# TL431A, B Series, NCV431A, B Series, SCV431A

## Programmable Precision References

The TL431A, B integrated circuits are three-terminal programmable shunt regulator diodes. These monolithic IC voltage references operate as a low temperature coefficient zener which is programmable from  $V_{ref}$  to 36 V with two external resistors. These devices exhibit a wide operating current range of 1.0 mA to 100 mA with a typical dynamic impedance of 0.22  $\Omega$ . The characteristics of these references make them excellent replacements for zener diodes in many applications such as digital voltmeters, power supplies, and op amp circuitry. The 2.5 V reference makes it convenient to obtain a stable reference from 5.0 V logic supplies, and since the TL431A, B operates as a shunt regulator, it can be used as either a positive or negative voltage reference.

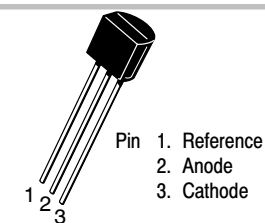
### Features

- Programmable Output Voltage to 36 V
- Voltage Reference Tolerance:  $\pm 0.4\%$ , Typ @ 25°C (TL431B)
- Low Dynamic Output Impedance, 0.22  $\Omega$  Typical
- Sink Current Capability of 1.0 mA to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/°C Typical
- Temperature Compensated for Operation over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- NCV/SCV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



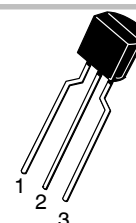
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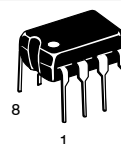
STRAIGHT LEAD  
BULK PACK

TO-92  
LP SUFFIX  
CASE 29-11



BENT LEAD  
TAPE & REEL  
AMMO PACK

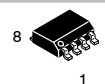
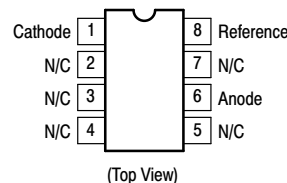
TO-92  
LPRA, LPRE, LPRM,  
LPRP SUFFIX  
CASE 29-11



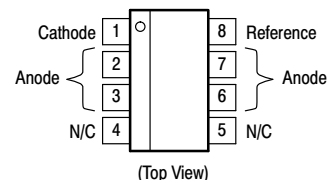
PDIP-8  
P SUFFIX  
CASE 626



Micro8™  
DM SUFFIX  
CASE 846A



SOIC-8  
D SUFFIX  
CASE 751



This is an internally modified SOIC-8 package. Pins 2, 3, 6 and 7 are electrically common to the die attach flag. This internal lead frame modification increases power dissipation capability when appropriately mounted on a printed circuit board. This modified package conforms to all external dimensions of the standard SOIC-8 package.

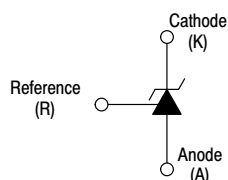
### ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

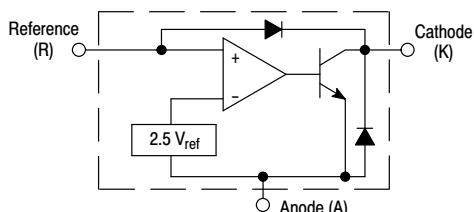
### DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 14 of this data sheet.

# TL431A, B Series, NCV431A, B Series, SCV431A

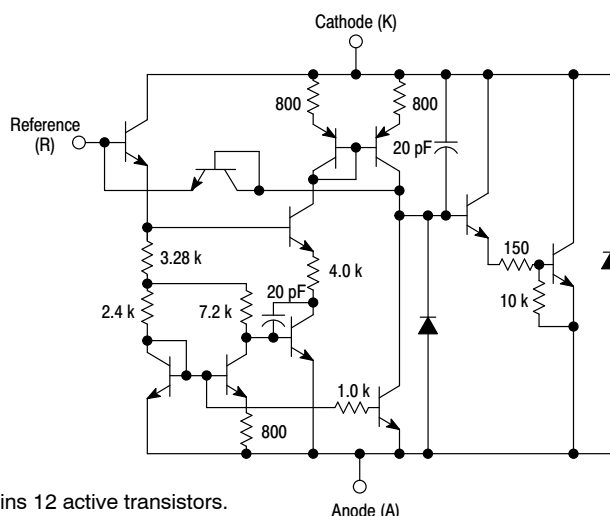


**Figure 1. Symbol**



**Figure 2. Representative Block Diagram**

This device contains 12 active transistors.



**Figure 3. Representative Schematic Diagram**

Component values are nominal

## MAXIMUM RATINGS (Full operating ambient temperature range applies, unless otherwise noted.)

| Rating                                                                                                                                                                                             | Symbol           | Value                                 | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|---------------------------------------|------|
| Cathode to Anode Voltage                                                                                                                                                                           | $V_{KA}$         | 37                                    | V    |
| Cathode Current Range, Continuous                                                                                                                                                                  | $I_K$            | -100 to +150                          | mA   |
| Reference Input Current Range, Continuous                                                                                                                                                          | $I_{ref}$        | -0.05 to +10                          | mA   |
| Operating Junction Temperature                                                                                                                                                                     | $T_J$            | 150                                   | °C   |
| Operating Ambient Temperature Range<br>TL431I, TL431AI, TL431BI<br>TL431C, TL431AC, TL431BC<br>NCV431AI, NCV431B, TL431BV, SCV431AI                                                                | $T_A$            | -40 to +85<br>0 to +70<br>-40 to +125 | °C   |
| Storage Temperature Range                                                                                                                                                                          | $T_{stg}$        | -65 to +150                           | °C   |
| Total Power Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ Ambient Temperature<br>D, LP Suffix Plastic Package<br>P Suffix Plastic Package<br>DM Suffix Plastic Package | $P_D$            | 0.70<br>1.10<br>0.52                  | W    |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ Case Temperature<br>D, LP Suffix Plastic Package<br>P Suffix Plastic Package                                 | $P_D$            | 1.5<br>3.0                            | W    |
| ESD Rating (Note 1)<br>Human Body Model per JEDEC JESD22-A114F<br>Machine Model per JEDEC JESD22-A115C<br>Charged Device Model per JEDEC JESD22-C101E                                              | HBM<br>MM<br>CDM | >2000<br>>200<br>>500                 | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. This device contains latch-up protection and exceeds  $\pm 100$  mA per JEDEC standard JESD78.

## RECOMMENDED OPERATING CONDITIONS

| Condition                | Symbol   | Min       | Max | Unit |
|--------------------------|----------|-----------|-----|------|
| Cathode to Anode Voltage | $V_{KA}$ | $V_{ref}$ | 36  | V    |
| Cathode Current          | $I_K$    | 1.0       | 100 | mA   |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# TL431A, B Series, NCV431A, B Series, SCV431A

## THERMAL CHARACTERISTICS

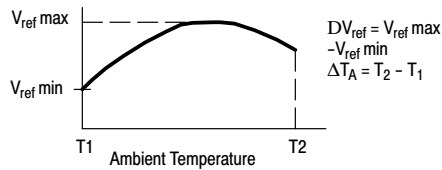
| Characteristic                          | Symbol          | D, LP Suffix Package | P Suffix Package | DM Suffix Package | Unit                        |
|-----------------------------------------|-----------------|----------------------|------------------|-------------------|-----------------------------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 178                  | 114              | 240               | $^{\circ}\text{C}/\text{W}$ |
| Thermal Resistance, Junction-to-Case    | $R_{\theta JC}$ | 83                   | 41               | –                 | $^{\circ}\text{C}/\text{W}$ |

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.)

| Characteristic                                                                                                                                                                                                           | Symbol                                 | TL431I       |              |              | TL431C        |              |               | Unit          |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------|--------------|--------------|--------------|---------------|--------------|---------------|---------------|
|                                                                                                                                                                                                                          |                                        | Min          | Typ          | Max          | Min           | Typ          | Max           |               |
| Reference Input Voltage (Figure 1)<br>$V_{KA} = V_{ref}$ , $I_K = 10 \text{ mA}$<br>$T_A = 25^{\circ}\text{C}$<br>$T_A = T_{low}$ to $T_{high}$ (Note 2)                                                                 | $V_{ref}$                              | 2.44<br>2.41 | 2.495<br>–   | 2.55<br>2.58 | 2.44<br>2.423 | 2.495<br>–   | 2.55<br>2.567 | V             |
| Reference Input Voltage Deviation Over Temperature Range (Figure 1, Notes 3, 4)<br>$V_{KA} = V_{ref}$ , $I_K = 10 \text{ mA}$                                                                                            | $\Delta V_{ref}$                       | –            | 7.0          | 30           | –             | 3.0          | 17            | mV            |
| Ratio of Change in Reference Input Voltage to Change in Cathode to Anode Voltage<br>$I_K = 10 \text{ mA}$ (Figure 2),<br>$\Delta V_{KA} = 10 \text{ V}$ to $V_{ref}$<br>$\Delta V_{KA} = 36 \text{ V}$ to $10 \text{ V}$ | $\frac{\Delta V_{ref}}{\Delta V_{KA}}$ | –<br>–       | –1.4<br>–1.0 | –2.7<br>–2.0 | –<br>–        | –1.4<br>–1.0 | –2.7<br>–2.0  | mV/V          |
| Reference Input Current (Figure 2)<br>$I_K = 10 \text{ mA}$ , $R_1 = 10 \text{ k}$ , $R_2 = \infty$<br>$T_A = 25^{\circ}\text{C}$<br>$T_A = T_{low}$ to $T_{high}$ (Note 2)                                              | $I_{ref}$                              | –<br>–       | 1.8<br>–     | 4.0<br>6.5   | –<br>–        | 1.8<br>–     | 4.0<br>5.2    | $\mu\text{A}$ |
| Reference Input Current Deviation Over Temperature Range (Figure 2, Note 3)<br>$I_K = 10 \text{ mA}$ , $R_1 = 10 \text{ k}$ , $R_2 = \infty$                                                                             | $\Delta I_{ref}$                       | –            | 0.8          | 2.5          | –             | 0.4          | 1.2           | $\mu\text{A}$ |
| Minimum Cathode Current For Regulation<br>$V_{KA} = V_{ref}$ (Figure 1)                                                                                                                                                  | $I_{min}$                              | –            | 0.5          | 1.0          | –             | 0.5          | 1.0           | mA            |
| Off-State Cathode Current (Figure 3)<br>$V_{KA} = 36 \text{ V}$ , $V_{ref} = 0 \text{ V}$                                                                                                                                | $I_{off}$                              | –            | 20           | 1000         | –             | 20           | 1000          | nA            |
| Dynamic Impedance (Figure 1, Note 5)<br>$V_{KA} = V_{ref}$ , $\Delta I_K = 1.0 \text{ mA}$ to $100 \text{ mA}$ , $f \leq 1.0 \text{ kHz}$                                                                                | $ Z_{KA} $                             | –            | 0.22         | 0.5          | –             | 0.22         | 0.5           | $\Omega$      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- $T_{low} = -40^{\circ}\text{C}$  for TL431AIP, TL431AILP, TL431IP, TL431ILP, TL431BID, TL431BIP, TL431BILP, TL431AIDM, TL431IDM, TL431BIDM;  
 $= 0^{\circ}\text{C}$  for TL431ACP, TL431ACLP, TL431CP, TL431CLP, TL431CD, TL431ACD, TL431BCD, TL431BCP, TL431BCLP, TL431CDM, TL431ACDM, TL431BCDM  
 $T_{high} = +85^{\circ}\text{C}$  for TL431AIP, TL431AILP, TL431IP, TL431ILP, TL431BID, TL431BIP, TL431BILP, TL431IDM, TL431AIDM, TL431BIDM  
 $= +70^{\circ}\text{C}$  for TL431ACP, TL431ACLP, TL431CP, TL431ACD, TL431BCD, TL431BCP, TL431BCLP, TL431CDM, TL431ACDM, TL431BCDM
- Guaranteed by design.
- The deviation parameter  $\Delta V_{ref}$  is defined as the difference between the maximum and minimum values obtained over the full operating ambient temperature range that applies.



The average temperature coefficient of the reference input voltage,  $\alpha V_{ref}$  is defined as:

$$V_{ref} \frac{\text{ppm}}{^{\circ}\text{C}} = \frac{\left( \frac{\Delta V_{ref}}{V_{ref} @ 25^{\circ}\text{C}} \right) \times 10^6}{\Delta T_A} = \frac{\Delta V_{ref} \times 10^6}{\Delta T_A (V_{ref} @ 25^{\circ}\text{C})}$$

$\alpha V_{ref}$  can be positive or negative depending on whether  $V_{ref} \text{ Min}$  or  $V_{ref} \text{ Max}$  occurs at the lower ambient temperature. (Refer to Figure 6.)

Example :  $\Delta V_{ref} = 8.0 \text{ mV}$  and slope is positive,

$$V_{ref} @ 25^{\circ}\text{C} = 2.495 \text{ V}, \Delta T_A = 70^{\circ}\text{C}$$

$$\alpha V_{ref} = \frac{0.008 \times 10^6}{70 (2.495)} = 45.8 \text{ ppm}/^{\circ}\text{C}$$

- The dynamic impedance  $Z_{KA}$  is defined as:  $|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$ . When the device is programmed with two external resistors,  $R_1$  and  $R_2$ ,

(refer to Figure 2) the total dynamic impedance of the circuit is defined as:  $|Z_{KA}'| \approx |Z_{KA}| \left( 1 + \frac{R_1}{R_2} \right)$

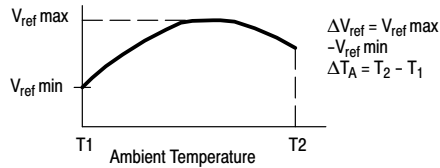
# TL431A, B Series, NCV431A, B Series, SCV431A

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise noted.)

| Characteristic                                                                                                                                                                                              | Symbol                                 | TL431AI /<br>NCV431AI/<br>SCV431AI |              |              | TL431AC       |              |               | TL431BC / TL431BI /<br>TL431BV /<br>NCV431BV |                |                | Unit |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------|------------------------------------|--------------|--------------|---------------|--------------|---------------|----------------------------------------------|----------------|----------------|------|
|                                                                                                                                                                                                             |                                        | Min                                | Typ          | Max          | Min           | Typ          | Max           | Min                                          | Typ            | Max            |      |
| Reference Input Voltage (Figure 1)<br>V <sub>KA</sub> = V <sub>ref</sub> , I <sub>K</sub> = 10 mA<br>T <sub>A</sub> = 25°C<br>T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 6)               | V <sub>ref</sub>                       | 2.47<br>2.44                       | 2.495<br>–   | 2.52<br>2.55 | 2.47<br>2.453 | 2.495<br>–   | 2.52<br>2.537 | 2.485<br>2.475                               | 2.495<br>2.495 | 2.505<br>2.515 | V    |
| Reference Input Voltage Deviation Over<br>Temperature Range (Figure 1, Notes 7, 8)<br>V <sub>KA</sub> = V <sub>ref</sub> , I <sub>K</sub> = 10 mA                                                           | ΔV <sub>ref</sub>                      | –                                  | 7.0          | 30           | –             | 3.0          | 17            | –                                            | 3.0            | 17             | mV   |
| Ratio of Change in Reference Input Voltage to<br>Change in Cathode to Anode Voltage<br>I <sub>K</sub> = 10 mA (Figure 2),<br>ΔV <sub>KA</sub> = 10 V to V <sub>ref</sub><br>ΔV <sub>KA</sub> = 36 V to 10 V | $\frac{\Delta V_{ref}}{\Delta V_{KA}}$ | –<br>–                             | –1.4<br>–1.0 | –2.7<br>–2.0 | –<br>–        | –1.4<br>–1.0 | –2.7<br>–2.0  | –<br>–                                       | –1.4<br>–1.0   | –2.7<br>–2.0   | mV/V |
| Reference Input Current (Figure 2)<br>I <sub>K</sub> = 10 mA, R1 = 10 k, R2 = ∞<br>T <sub>A</sub> = 25°C<br>T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 6)                                 | I <sub>ref</sub>                       | –<br>–                             | 1.8<br>–     | 4.0<br>6.5   | –<br>–        | 1.8<br>–     | 4.0<br>5.2    | –<br>–                                       | 1.1<br>–       | 2.0<br>4.0     | μA   |
| Reference Input Current Deviation Over<br>Temperature Range (Figure 2, Note 7)<br>I <sub>K</sub> = 10 mA, R1 = 10 k, R2 = ∞                                                                                 | ΔI <sub>ref</sub>                      | –                                  | 0.8          | 2.5          | –             | 0.4          | 1.2           | –                                            | 0.8            | 2.5            | μA   |
| Minimum Cathode Current For Regulation<br>V <sub>KA</sub> = V <sub>ref</sub> (Figure 1)                                                                                                                     | I <sub>min</sub>                       | –                                  | 0.5          | 1.0          | –             | 0.5          | 1.0           | –                                            | 0.5            | 1.0            | mA   |
| Off-State Cathode Current (Figure 3)<br>V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0 V                                                                                                                      | I <sub>off</sub>                       | –                                  | 20           | 1000         | –             | 20           | 1000          | –                                            | 0.23           | 500            | nA   |
| Dynamic Impedance (Figure 1, Note 9)<br>V <sub>KA</sub> = V <sub>ref</sub> , ΔI <sub>K</sub> = 1.0 mA to 100 mA<br>f ≤ 1.0 kHz                                                                              | Z <sub>KA</sub>                        | –                                  | 0.22         | 0.5          | –             | 0.22         | 0.5           | –                                            | 0.14           | 0.3            | Ω    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. T<sub>low</sub> = –40°C for TL431AIP, TL431AILP, TL431IP, TL431ILP, TL431BID, TL431BIP, TL431BILP, TL431BV, TL431AIDM, TL431IDM, TL431BIDM, NCV431AIDMR2G, NCV431AIDR2G, NCV431BVDR2G, SCV431AIDMR2G  
= 0°C for TL431ACP, TL431ACLP, TL431CP, TL431CLP, TL431CD, TL431ACD, TL431BCD, TL431BCP, TL431BCLP, TL431CDM, TL431ACDM, TL431BCDM, SCV431AIDMR2G  
T<sub>high</sub> = +85°C for TL431AIP, TL431AILP, TL431IP, TL431ILP, TL431BID, TL431BIP, TL431BILP, TL431IDM, TL431AIDM, TL431BIDM  
= +70°C for TL431ACP, TL431ACLP, TL431CP, TL431ACD, TL431BCD, TL431BCP, TL431BCLP, TL431CDM, TL431ACDM, TL431BCDM  
= +125°C TL431BV, NCV431AIDMR2G, NCV431AIDR2G, NCV431BVDR2G, NCV431BVDR2G, SCV431AIDMR2G
7. Guaranteed by design.
8. The deviation parameter ΔV<sub>ref</sub> is defined as the difference between the maximum and minimum values obtained over the full operating ambient temperature range that applies.



The average temperature coefficient of the reference input voltage, αV<sub>ref</sub> is defined as:

$$V_{ref} \frac{\text{ppm}}{^{\circ}\text{C}} = \frac{\left( \frac{\Delta V_{ref}}{V_{ref} @ 25^{\circ}\text{C}} \right) \times 10^6}{\Delta T_A} = \frac{\Delta V_{ref} \times 10^6}{\Delta T_A (V_{ref} @ 25^{\circ}\text{C})}$$

αV<sub>ref</sub> can be positive or negative depending on whether V<sub>ref</sub> Min or V<sub>ref</sub> Max occurs at the lower ambient temperature. (Refer to Figure 6.)

Example : ΔV<sub>ref</sub> = 8.0 mV and slope is positive,

$$V_{ref} @ 25^{\circ}\text{C} = 2.495 \text{ V}, \Delta T_A = 70^{\circ}\text{C}$$

$$\alpha V_{ref} = \frac{0.008 \times 10^6}{70 (2.495)} = 45.8 \text{ ppm}/^{\circ}\text{C}$$

9. The dynamic impedance Z<sub>KA</sub> is defined as  $|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$  When the device is programmed with two external resistors, R1 and R2, (refer

to Figure 2) the total dynamic impedance of the circuit is defined as:  $|Z_{KA}'| \approx |Z_{KA}| \left( 1 + \frac{R1}{R2} \right)$

10. NCV431AIDMR2G, NCV431AIDR2G, NCV431BVDR2G, NCV431BVDR2G, SCV431AIDMR2G T<sub>low</sub> = –40°C, T<sub>high</sub> = +125°C.  
NCV prefix is for automotive and other applications requiring unique site and control change requirements.

# TL431A, B Series, NCV431A, B Series, SCV431A

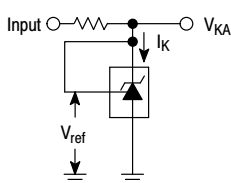


Figure 1. Test Circuit for  $V_{KA} = V_{ref}$

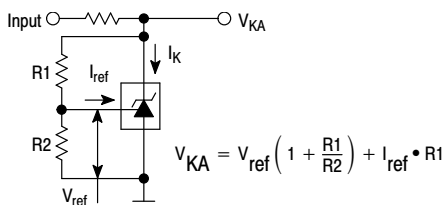


Figure 2. Test Circuit for  $V_{KA} > V_{ref}$

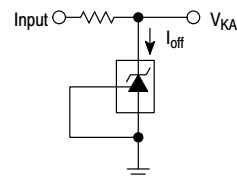


Figure 3. Test Circuit for  $I_{off}$

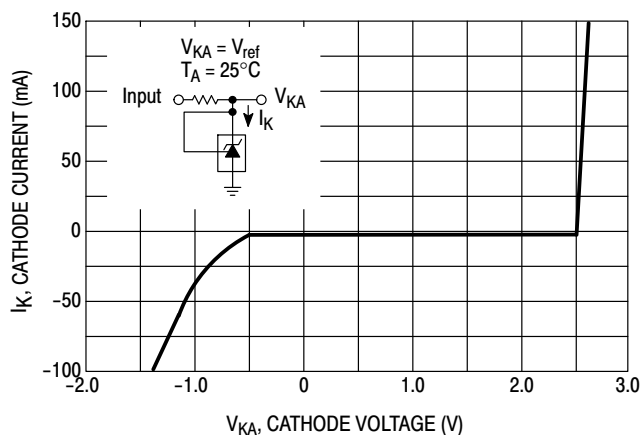


Figure 4. Cathode Current versus Cathode Voltage

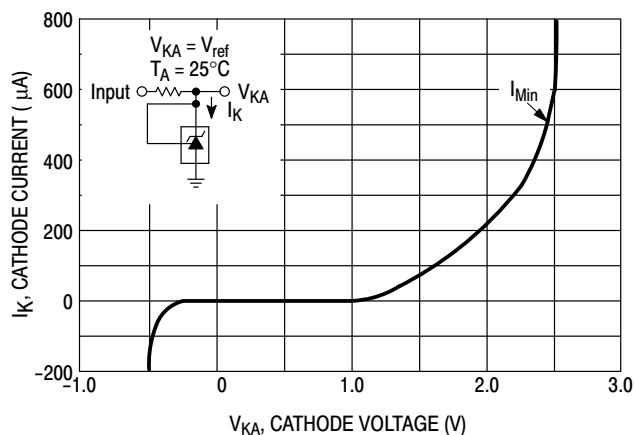


Figure 5. Cathode Current versus Cathode Voltage

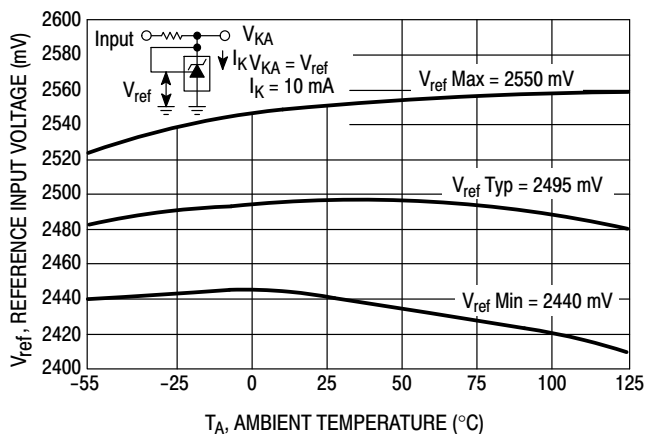


Figure 6. Reference Input Voltage versus Ambient Temperature

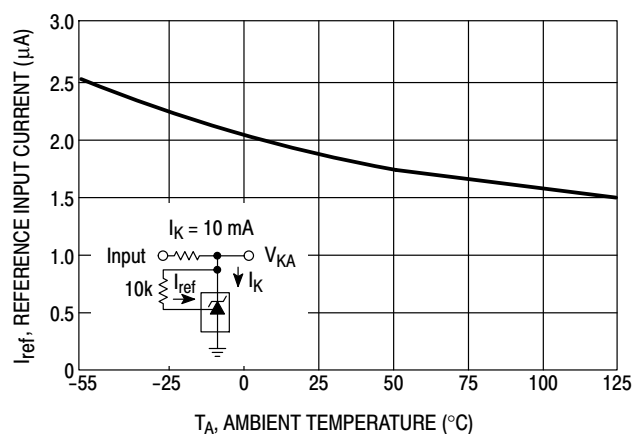
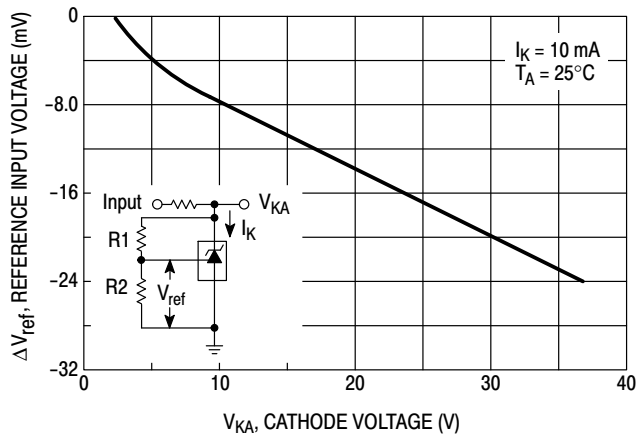
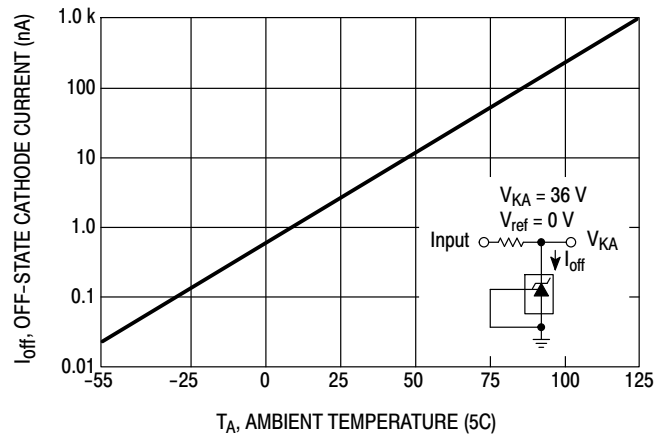


Figure 7. Reference Input Current versus Ambient Temperature

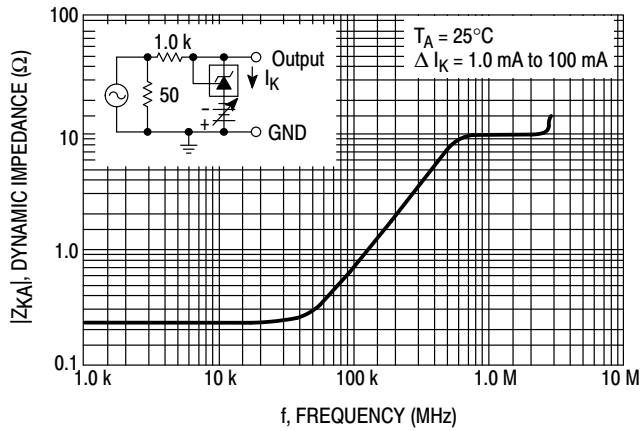
# TL431A, B Series, NCV431A, B Series, SCV431A



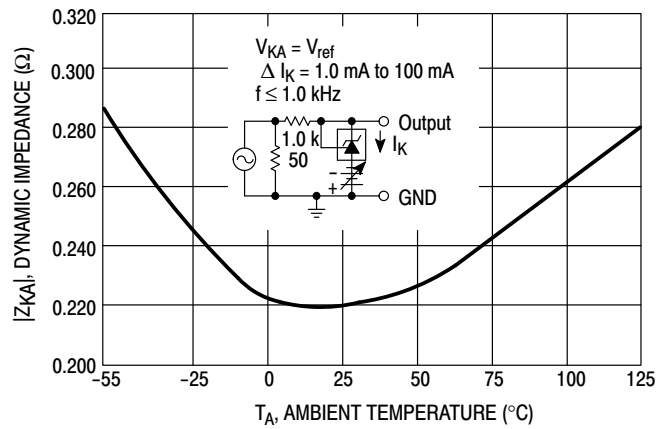
**Figure 8. Change in Reference Input Voltage versus Cathode Voltage**



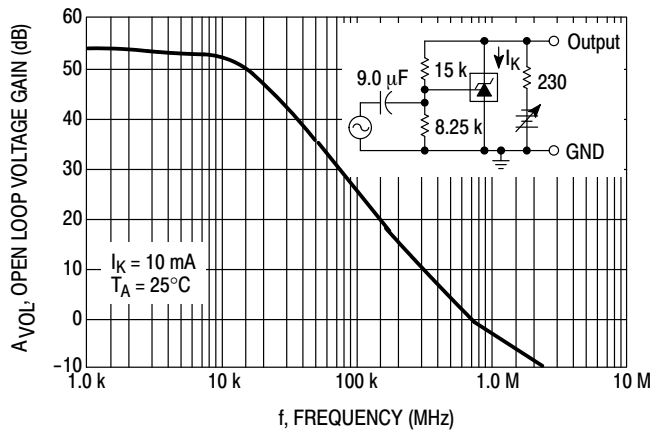
**Figure 9. Off-State Cathode Current versus Ambient Temperature**



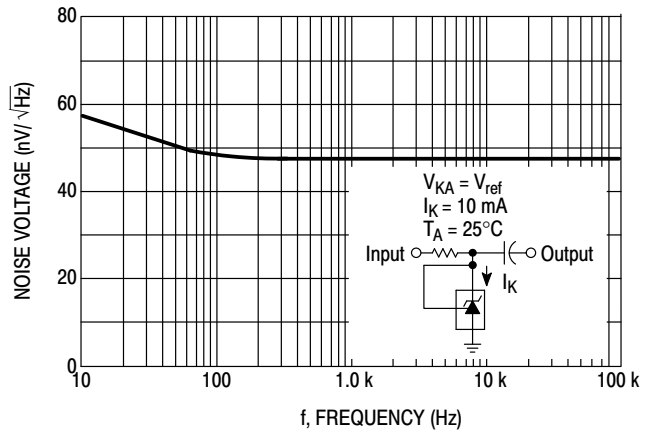
**Figure 10. Dynamic Impedance versus Frequency**



**Figure 11. Dynamic Impedance versus Ambient Temperature**



**Figure 12. Open-Loop Voltage Gain versus Frequency**



**Figure 13. Spectral Noise Density**

# TL431A, B Series, NCV431A, B Series, SCV431A

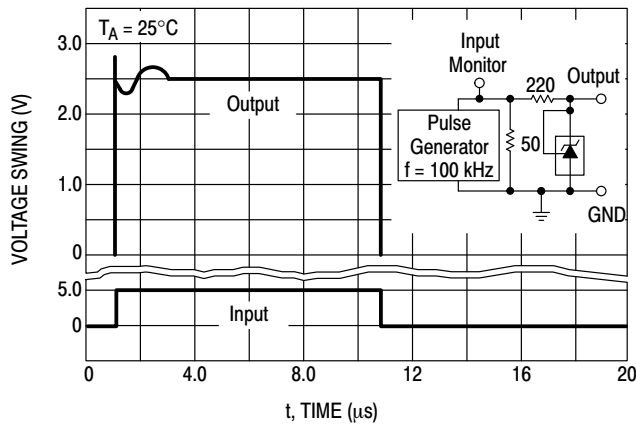


Figure 14. Pulse Response

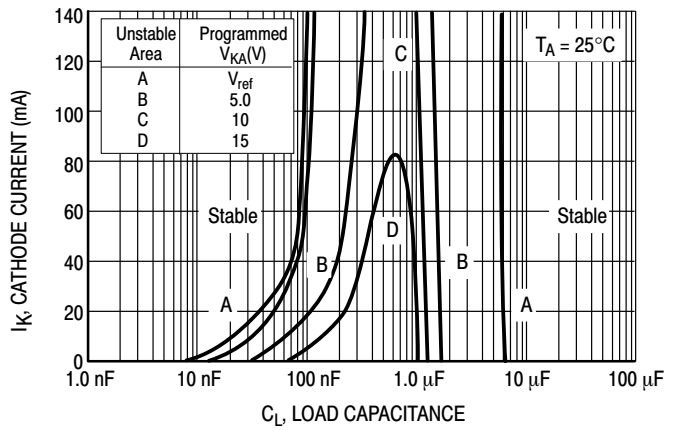


Figure 15. Stability Boundary Conditions

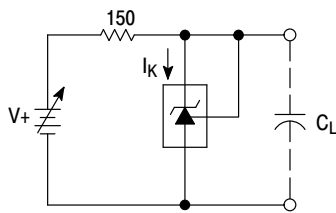


Figure 16. Test Circuit For Curve A of Stability Boundary Conditions

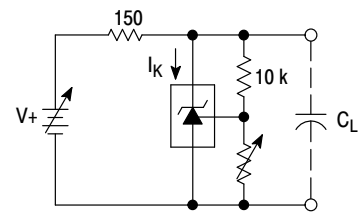


Figure 17. Test Circuit For Curves B, C, And D of Stability Boundary Conditions

## TYPICAL APPLICATIONS

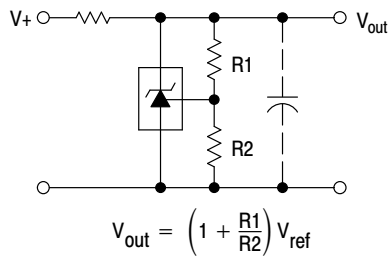


Figure 18. Shunt Regulator

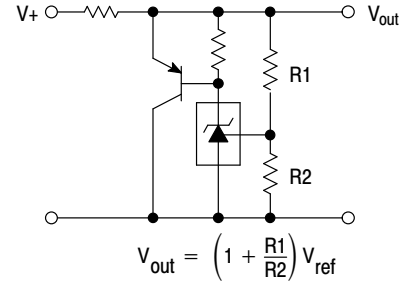
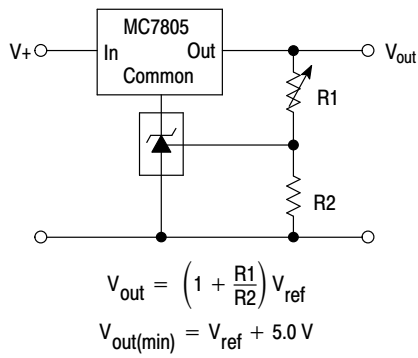
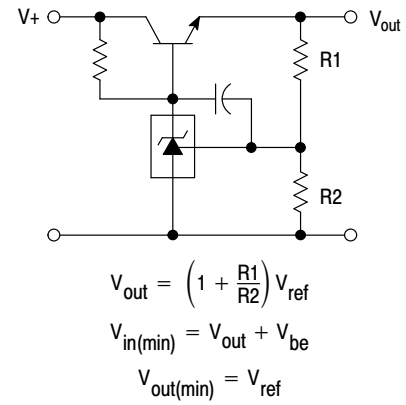


Figure 19. High Current Shunt Regulator

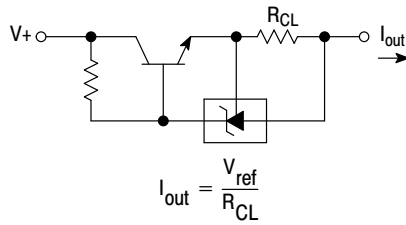
# TL431A, B Series, NCV431A, B Series, SCV431A



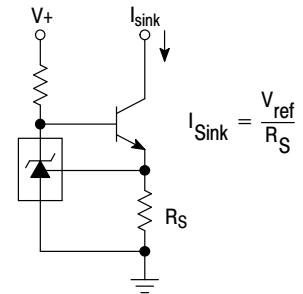
**Figure 20. Output Control for a Three-Terminal Fixed Regulator**



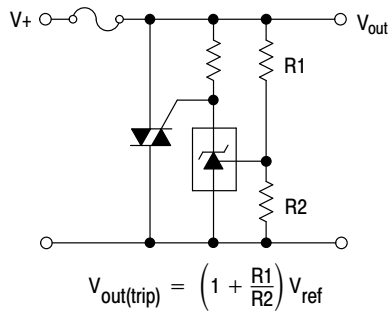
**Figure 21. Series Pass Regulator**



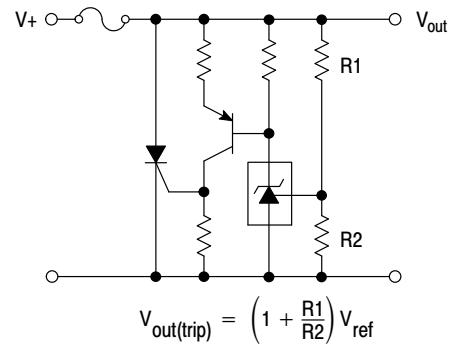
**Figure 22. Constant Current Source**



**Figure 23. Constant Current Sink**



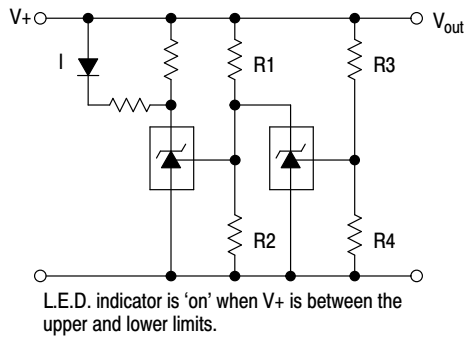
**Figure 24. TRIAC Crowbar**



**Figure 25. SRC Crowbar**



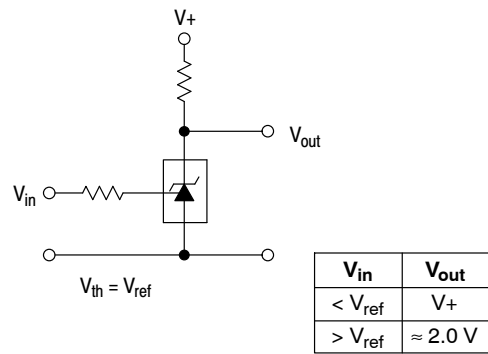
# TL431A, B Series, NCV431A, B Series, SCV431A



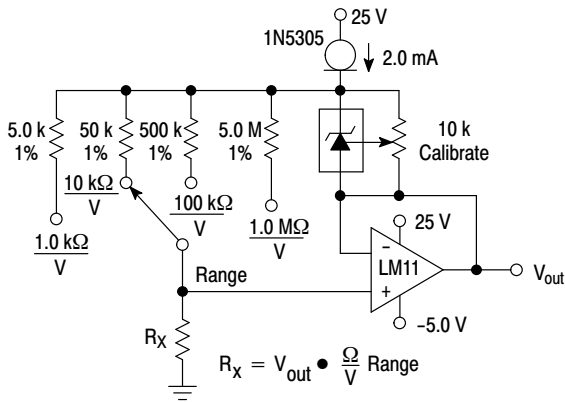
$$\text{Lower Limit} = \left(1 + \frac{R1}{R2}\right) V_{\text{ref}}$$

$$\text{Upper Limit} = \left(1 + \frac{R3}{R4}\right) V_{\text{ref}}$$

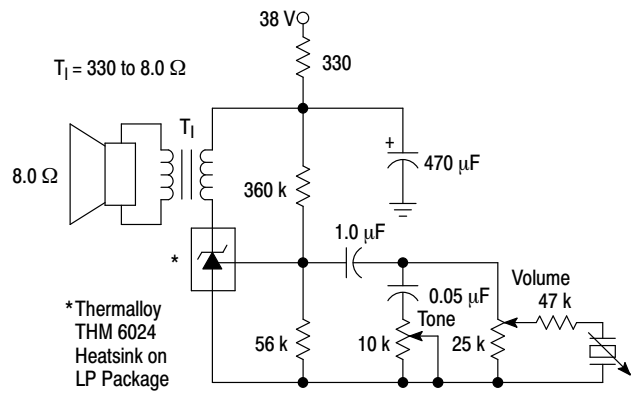
**Figure 26. Voltage Monitor**



**Figure 27. Single-Supply Comparator with Temperature-Compensated Threshold**

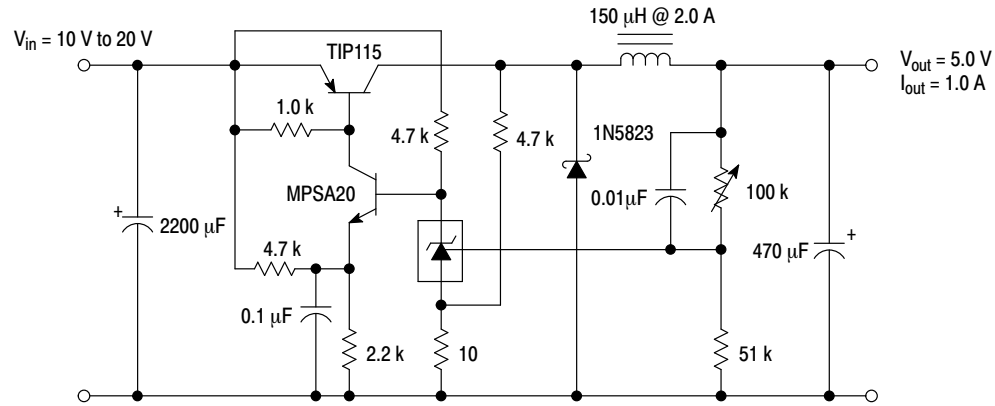


**Figure 28. Linear Ohmmeter**



**Figure 29. Simple 400 mW Phono Amplifier**

# TL431A, B Series, NCV431A, B Series, SCV431A



**Figure 30. High Efficiency Step-Down Switching Converter**

| Test            | Conditions                                                    | Results           |
|-----------------|---------------------------------------------------------------|-------------------|
| Line Regulation | $V_{in} = 10 \text{ V to } 20 \text{ V}, I_o = 1.0 \text{ A}$ | 53 mV (1.1%)      |
| Load Regulation | $V_{in} = 15 \text{ V}, I_o = 0 \text{ A to } 1.0 \text{ A}$  | 25 mV (0.5%)      |
| Output Ripple   | $V_{in} = 10 \text{ V}, I_o = 1.0 \text{ A}$                  | 50 mVpp P.A.R.D.  |
| Output Ripple   | $V_{in} = 20 \text{ V}, I_o = 1.0 \text{ A}$                  | 100 mVpp P.A.R.D. |
| Efficiency      | $V_{in} = 15 \text{ V}, I_o = 1.0 \text{ A}$                  | 82%               |

## APPLICATIONS INFORMATION

The TL431 is a programmable precision reference which is used in a variety of ways. It serves as a reference voltage in circuits where a non-standard reference voltage is needed. Other uses include feedback control for driving an optocoupler in power supplies, voltage monitor, constant current source, constant current sink and series pass regulator. In each of these applications, it is critical to maintain stability of the device at various operating currents and load capacitances. In some cases the circuit designer can estimate the stabilization capacitance from the stability boundary conditions curve provided in Figure 15. However, these typical curves only provide stability information at specific cathode voltages and at a specific load condition. Additional information is needed to determine the capacitance needed to optimize phase margin or allow for process variation.

A simplified model of the TL431 is shown in Figure 31. When tested for stability boundaries, the load resistance is 150  $\Omega$ . The model reference input consists of an input transistor and a dc emitter resistance connected to the device anode. A dependent current source,  $G_m$ , develops a current whose amplitude is determined by the difference between the 1.78 V internal reference voltage source and the input transistor emitter voltage. A portion of  $G_m$  flows through compensation capacitance,  $C_{P2}$ . The voltage across  $C_{P2}$  drives the output dependent current source,  $G_o$ , which is connected across the device cathode and anode.

Model component values are:

$$V_{ref} = 1.78 \text{ V}$$

$$G_m = 0.3 + 2.7 \exp(-I_C/26 \text{ mA})$$

where  $I_C$  is the device cathode current and  $G_m$  is in mhos

$$G_o = 1.25 (V_{cp2}) \mu\text{mhos}.$$

Resistor and capacitor typical values are shown on the model. Process tolerances are  $\pm 20\%$  for resistors,  $\pm 10\%$  for capacitors, and  $\pm 40\%$  for transconductances.

An examination of the device model reveals the location of circuit poles and zeroes:

$$P_1 = \frac{1}{2\pi R_{GM} C_{P1}} = \frac{1}{2\pi * 1.0 \text{ M} * 20 \text{ pF}} = 7.96 \text{ kHz}$$

$$P_2 = \frac{1}{2\pi R_{P2} C_{P2}} = \frac{1}{2\pi * 10 \text{ M} * 0.265 \text{ pF}} = 60 \text{ kHz}$$

$$Z_1 = \frac{1}{2\pi R_{Z1} C_{P1}} = \frac{1}{2\pi * 15.9 \text{ k} * 20 \text{ pF}} = 500 \text{ kHz}$$

In addition, there is an external circuit pole defined by the load:

$$P_L = \frac{1}{2\pi R_L C_L}$$

Also, the transfer dc voltage gain of the TL431 is:

$$G = G_M R_{GM} G_o R_L$$

Example 1:

$I_C = 10 \text{ mA}$ ,  $R_L = 230 \Omega$ ,  $C_L = 0$ . Define the transfer gain.

The DC gain is:

$$G = G_M R_{GM} G_o R_L = (2.138)(1.0 \text{ M})(1.25 \mu)(230) = 615 = 56 \text{ dB}$$

$$\text{Loop gain} = G \frac{8.25 \text{ k}}{8.25 \text{ k} + 15 \text{ k}} = 218 = 47 \text{ dB}$$

The resulting transfer function Bode plot is shown in Figure 32. The asymptotic plot may be expressed as the following equation:

$$A_v = 615 \frac{\left(1 + \frac{jf}{500 \text{ kHz}}\right)}{\left(1 + \frac{jf}{8.0 \text{ kHz}}\right)\left(1 + \frac{jf}{60 \text{ kHz}}\right)}$$

The Bode plot shows a unity gain crossover frequency of approximately 600 kHz. The phase margin, calculated from the equation, would be 55.9 degrees. This model matches the Open-Loop Bode Plot of Figure 12. The total loop would have a unity gain frequency of about 300 kHz with a phase margin of about 44 degrees.

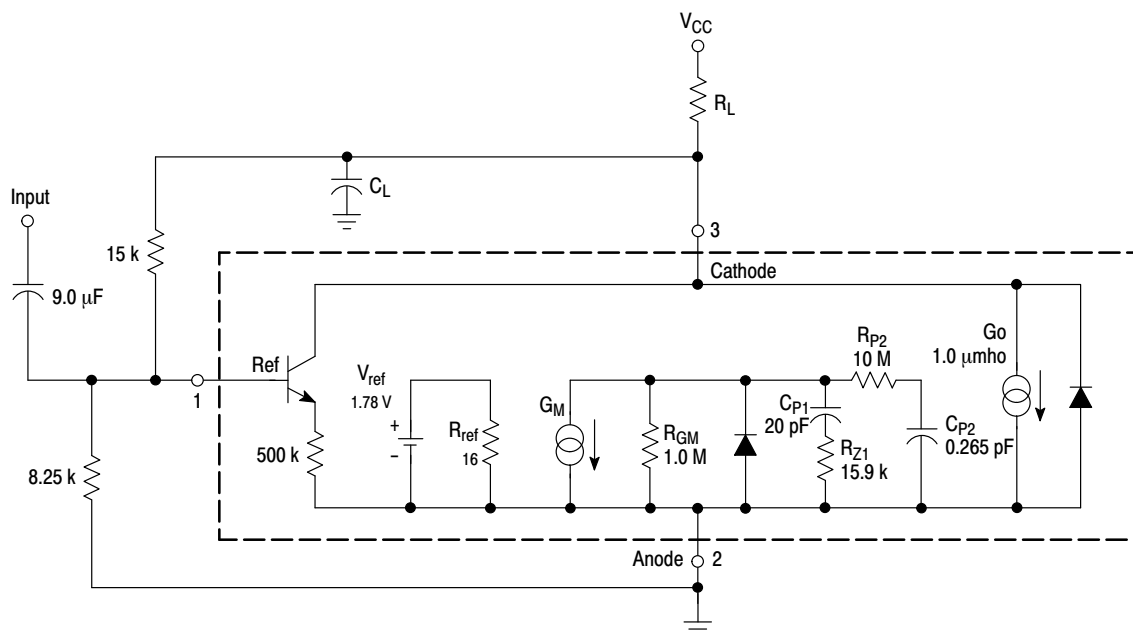


Figure 31. Simplified TL431 Device Model

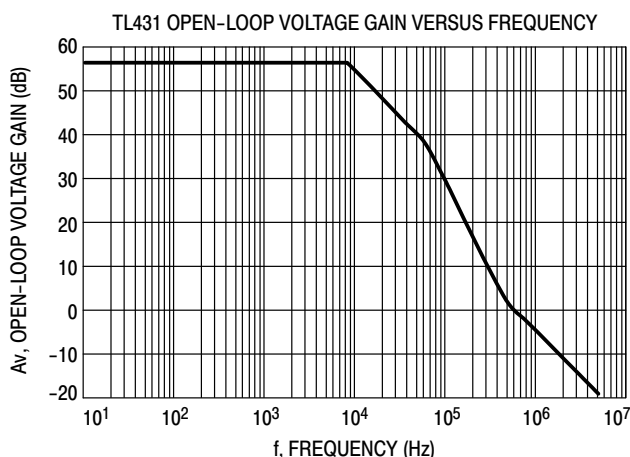


Figure 32. Example 1 Circuit Open Loop Gain Plot

Example 2.

$I_C = 7.5 \text{ mA}$ ,  $R_L = 2.2 \text{ k}\Omega$ ,  $C_L = 0.01 \text{ }\mu\text{F}$ . Cathode tied to reference input pin. An examination of the data sheet stability boundary curve (Figure 15) shows that this value of load capacitance and cathode current is on the boundary. Define the transfer gain.

The DC gain is:

$$G = G_M R_{GM} G_O R_L =$$

$$(2.323)(1.0 \text{ M})(1.25 \text{ }\mu)(2200) = 6389 = 76 \text{ dB}$$

The resulting open loop Bode plot is shown in Figure 33. The asymptotic plot may be expressed as the following equation:

$$A_v = 615 \frac{\left(1 + \frac{jf}{500 \text{ kHz}}\right)}{\left(1 + \frac{jf}{8.0 \text{ kHz}}\right)\left(1 + \frac{jf}{60 \text{ kHz}}\right)\left(1 + \frac{jf}{7.2 \text{ kHz}}\right)}$$

Note that the transfer function now has an extra pole formed by the load capacitance and load resistance.

Note that the crossover frequency in this case is about 250 kHz, having a phase margin of about  $-46$  degrees. Therefore, instability of this circuit is likely.

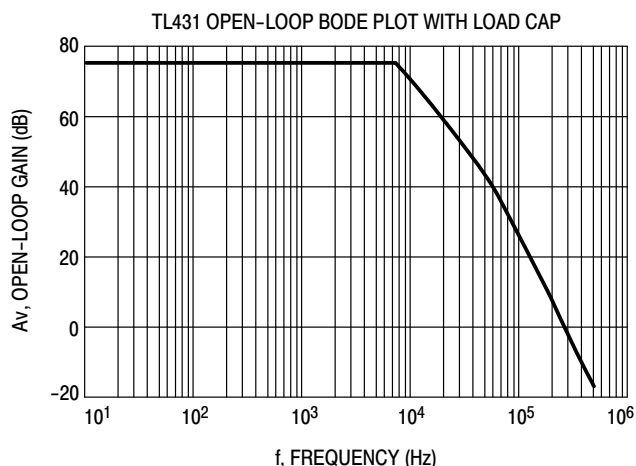


Figure 33. Example 2 Circuit Open Loop Gain Plot

With three poles, this system is unstable. The only hope for stabilizing this circuit is to add a zero. However, that can only be done by adding a series resistance to the output capacitance, which will reduce its effectiveness as a noise filter. Therefore, practically, in reference voltage applications, the best solution appears to be to use a smaller value of capacitance in low noise applications or a very large value to provide noise filtering and a dominant pole rolloff of the system.

# TL431A, B Series, NCV431A, B Series, SCV431A

## ORDERING INFORMATION

| Device       | Marking Code | Operating Temperature Range | Package Code           | Shipping Information†  | Tolerance           |
|--------------|--------------|-----------------------------|------------------------|------------------------|---------------------|
| TL431ACDG    | AC           | 0°C to 70°C                 | SOIC–8<br>(Pb–Free)    | 98 Units / Rail        | 1.0%                |
| TL431BCDG    | BC           |                             |                        |                        | 0.4%                |
| TL431CDG     | C            |                             |                        |                        | 2.2%                |
| TL431ACDR2G  | AC           |                             |                        | 2500 / Tape & Reel     | 1.0%                |
| TL431BCDR2G  | BC           |                             |                        |                        | 0.4%                |
| TL431CDR2G   | C            |                             |                        |                        | 2.2%                |
| TL431ACDMR2G | TAC          |                             | Micro8<br>(Pb–Free)    | 4000 / Tape & Reel     | 1.0%                |
| TL431BCDMR2G | TBC          |                             |                        |                        | 0.4%                |
| TL431CDMR2G  | T–C          |                             |                        |                        | 2.2%                |
| TL431ACPG    | ACP          |                             | PDIP–8<br>(Pb–Free)    | 50 Units / Rail        | 1.0%                |
| TL431BCPG    | BCP          |                             |                        |                        | 0.4%                |
| TL431CPG     | CP           |                             |                        |                        | 2.2%                |
| TL431ACLPG   | ACLP         |                             | TO–92<br>(Pb–Free)     | 2000 Units / Bag       | 1.0%                |
| TL431BCLPG   | BCLP         |                             |                        |                        | 0.4%                |
| TL431CLPG    | CLP          |                             |                        |                        | 2.2%                |
| TL431ACLPRAG | ACLP         |                             |                        | 2000 / Tape & Reel     | 1.0%                |
| TL431BCLPRAG | BCLP         |                             |                        |                        | 0.4%                |
| TL431CLPRAG  | CLP          |                             |                        |                        | 2.2%                |
| TL431ACLPREG | ACLP         |                             |                        |                        | 1.0%                |
| TL431BCLPREG | BCLP         |                             |                        |                        | 0.4%                |
| TL431CLPREG  | CLP          |                             |                        |                        | 2.2%                |
| TL431ACLPRPG | ACLP         |                             |                        | 2000 / Tape & Ammo Box | 1.0%                |
| TL431BCLPRMG | BCLP         |                             |                        | 2000 / Fan–Fold        | 0.4%                |
| TL431CLPRMG  | CLP          |                             |                        |                        | 2.2%                |
| TL431CLPRPG  | CLP          |                             |                        |                        |                     |
| TL431AIDG    | AI           |                             |                        | –40°C to 85°C          | SOIC–8<br>(Pb–Free) |
| TL431BIDG    | BI           | 0.4%                        |                        |                        |                     |
| TL431IDG     | I            | 2.2%                        |                        |                        |                     |
| TL431AIDR2G  | AI           | 2500s / Tape & Reel         | 1.0%                   |                        |                     |
| TL431BIDR2G  | BI           |                             | 0.4%                   |                        |                     |
| TL431IDR2G   | I            |                             | 2.2%                   |                        |                     |
| TL431AIDMR2G | TAI          | Micro8<br>(Pb–Free)         | 4000 / Tape & Reel     |                        | 1.0%                |
| TL431BIDMR2G | TBI          |                             |                        |                        | 0.4%                |
| TL431IDMR2G  | T–I          |                             |                        |                        | 2.2%                |
| TL431AIPG    | AIP          | PDIP–8<br>(Pb–Free)         | 50 Units / Rail        |                        | 1.0%                |
| TL431BIPG    | BIP          |                             |                        |                        | 0.4%                |
| TL431IPG     | IP           |                             |                        |                        | 2.2%                |
| TL431AILPG   | AILP         | TO–92<br>(Pb–Free)          | 2000 Units / Bag       |                        | 1.0%                |
| TL431BILPG   | BILP         |                             |                        |                        | 0.4%                |
| TL431ILPG    | ILP          |                             |                        |                        | 2.2%                |
| TL431AILPRAG | AILP         |                             | 2000 / Tape & Reel     |                        | 1.0%                |
| TL431BILPRAG | BILP         |                             |                        |                        | 0.4%                |
| SC431ILPRAG  | ILP          |                             |                        |                        | 2.2%                |
| TL431ILPRAG  | ILP          |                             |                        |                        |                     |
| TL431AILPRMG | AILP         |                             | 2000 / Tape & Ammo Box |                        | 1.0%                |
| TL431AILPRPG |              |                             |                        |                        |                     |
| TL431ILPRPG  | ILP          |                             |                        |                        | 2.2%                |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV/SCV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

# TL431A, B Series, NCV431A, B Series, SCV431A

## ORDERING INFORMATION

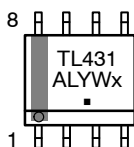
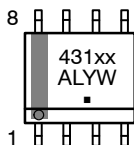
| Device         | Marking Code | Operating Temperature Range | Package Code        | Shipping Information <sup>†</sup> | Tolerance |
|----------------|--------------|-----------------------------|---------------------|-----------------------------------|-----------|
| TL431BVDG      | BV           | -40°C to 125°C              | SOIC-8<br>(Pb-Free) | 98 Units / Rail                   | 0.4%      |
| TL431BVDR2G    |              |                             |                     | 2500 / Tape & Reel                |           |
| TL431BVDMR2G   | TBV          |                             | Micro8<br>(Pb-Free) | 4000 / Tape & Reel                |           |
| TL431BVLPG     | BVL P        |                             | TO-92<br>(Pb-Free)  | 2000 Units / Bag                  |           |
| TL431BVLPRAG   |              |                             |                     | 2000 / Tape & Reel                |           |
| TL431BVPG      | BVP          |                             | PDIP-8<br>(Pb-Free) | 50 Units / Rail                   | 0.4%      |
| NCV431AIDMR2G* | RAN          |                             | Micro8<br>(Pb-Free) | 4000 / Tape & Reel                | 1%        |
| SCV431AIDMR2G* | RAP          |                             |                     | 2500 / Tape & Reel                |           |
| NCV431AIDR2G*  | AV           |                             | SOIC-8<br>(Pb-Free) | 2500 / Tape & Reel                | 0.4%      |
| NCV431BVDMR2G* | NVB          |                             | Micro8<br>(Pb-Free) | 4000 / Tape & Reel                |           |
| NCV431BVDR2G*  | BV           |                             | SOIC-8<br>(Pb-Free) | 2500 / Tape & Reel                |           |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV/SCV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

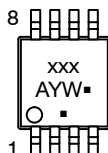
## MARKING DIAGRAMS

**SOIC-8  
D SUFFIX  
CASE 751**

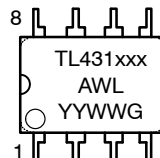


(Exception for the TL431CD and TL431ID only)

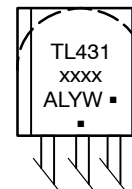
**Micro8  
CASE 846A**



**PDIP-8  
CASE 626**



**TO-92 (TO-226)  
CASE 29**



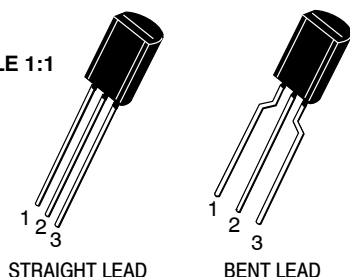
xxxx = See Specific Marking Code  
A = Assembly Location  
WL, L = Wafer Lot  
YY, Y = Year  
WW, W = Work Week  
▪ or G = Pb-Free Package  
(Note: Microdot may be in either location)

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®

ON

SCALE 1:1

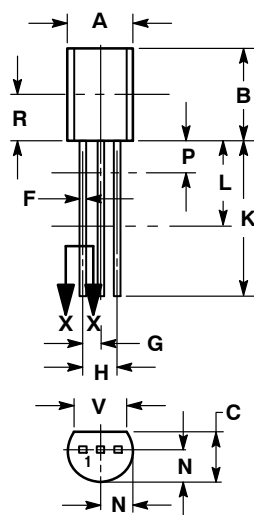


STRAIGHT LEAD

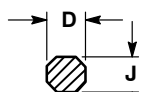
BENT LEAD

## TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE A

DATE 08 MAY 2012



STRAIGHT LEAD

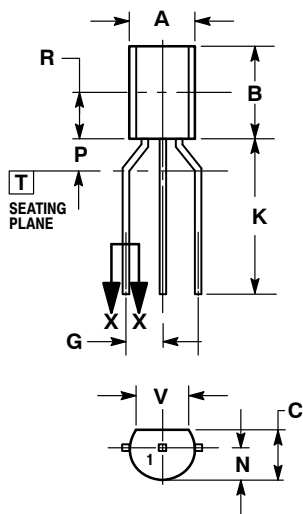


SECTION X-X

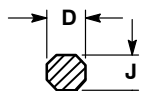
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES |       | MILLIMETERS |      |
|-----|--------|-------|-------------|------|
|     | MIN    | MAX   | MIN         | MAX  |
| A   | 0.175  | 0.205 | 4.44        | 5.21 |
| B   | 0.290  | 0.310 | 7.37        | 7.87 |
| C   | 0.125  | 0.165 | 3.18        | 4.19 |
| D   | 0.018  | 0.021 | 0.46        | 0.53 |
| F   | 0.016  | 0.019 | 0.41        | 0.48 |
| G   | 0.045  | 0.055 | 1.15        | 1.39 |
| H   | 0.095  | 0.105 | 2.42        | 2.66 |
| J   | 0.018  | 0.024 | 0.46        | 0.61 |
| K   | 0.500  | ---   | 12.70       | ---  |
| L   | 0.250  | ---   | 6.35        | ---  |
| N   | 0.080  | 0.105 | 2.04        | 2.66 |
| P   | ---    | 0.100 | ---         | 2.54 |
| R   | 0.135  | ---   | 3.43        | ---  |
| V   | 0.135  | ---   | 3.43        | ---  |



BENT LEAD



SECTION X-X

### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES |       | MILLIMETERS |      |
|-----|--------|-------|-------------|------|
|     | MIN    | MAX   | MIN         | MAX  |
| A   | 0.175  | 0.205 | 4.44        | 5.21 |
| B   | 0.290  | 0.310 | 7.37        | 7.87 |
| C   | 0.125  | 0.165 | 3.18        | 4.19 |
| D   | 0.018  | 0.021 | 0.46        | 0.53 |
| G   | 0.094  | 0.102 | 2.40        | 2.80 |
| J   | 0.018  | 0.024 | 0.46        | 0.61 |
| K   | 0.500  | ---   | 12.70       | ---  |
| N   | 0.080  | 0.105 | 2.04        | 2.66 |
| P   | ---    | 0.100 | ---         | 2.54 |
| R   | 0.135  | ---   | 3.43        | ---  |
| V   | 0.135  | ---   | 3.43        | ---  |

## STYLES ON PAGE 2

|                  |                       |                                                                                                                                                                                     |
|------------------|-----------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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| DESCRIPTION:     | TO-92 (TO-226) 1 WATT | PAGE 1 OF 2                                                                                                                                                                         |

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**TO-92 (TO-226) 1 WATT**  
**CASE 29-10**  
**ISSUE A**

DATE 08 MAY 2012

|                                                                        |                                                                             |                                                                     |                                                                        |                                                                    |
|------------------------------------------------------------------------|-----------------------------------------------------------------------------|---------------------------------------------------------------------|------------------------------------------------------------------------|--------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR           | <b>STYLE 2:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR                | <b>STYLE 3:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE           | <b>STYLE 4:</b><br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE            | <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE            |
| <b>STYLE 6:</b><br>PIN 1. GATE<br>2. SOURCE & SUBSTRATE<br>3. DRAIN    | <b>STYLE 7:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. GATE                     | <b>STYLE 8:</b><br>PIN 1. DRAIN<br>2. GATE<br>3. SOURCE & SUBSTRATE | <b>STYLE 9:</b><br>PIN 1. BASE 1<br>2. EMITTER<br>3. BASE 2            | <b>STYLE 10:</b><br>PIN 1. CATHODE<br>2. GATE<br>3. ANODE          |
| <b>STYLE 11:</b><br>PIN 1. ANODE<br>2. CATHODE & ANODE<br>3. CATHODE   | <b>STYLE 12:</b><br>PIN 1. MAIN TERMINAL 1<br>2. GATE<br>3. MAIN TERMINAL 2 | <b>STYLE 13:</b><br>PIN 1. ANODE 1<br>2. GATE<br>3. CATHODE 2       | <b>STYLE 14:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. BASE          | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. CATHODE<br>3. ANODE 2     |
| <b>STYLE 16:</b><br>PIN 1. ANODE<br>2. GATE<br>3. CATHODE              | <b>STYLE 17:</b><br>PIN 1. COLLECTOR<br>2. BASE<br>3. EMITTER               | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. CATHODE<br>3. NOT CONNECTED  | <b>STYLE 19:</b><br>PIN 1. GATE<br>2. ANODE<br>3. CATHODE              | <b>STYLE 20:</b><br>PIN 1. NOT CONNECTED<br>2. CATHODE<br>3. ANODE |
| <b>STYLE 21:</b><br>PIN 1. COLLECTOR<br>2. EMITTER<br>3. BASE          | <b>STYLE 22:</b><br>PIN 1. SOURCE<br>2. GATE<br>3. DRAIN                    | <b>STYLE 23:</b><br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN            | <b>STYLE 24:</b><br>PIN 1. EMITTER<br>2. COLLECTOR/ANODE<br>3. CATHODE | <b>STYLE 25:</b><br>PIN 1. MT 1<br>2. GATE<br>3. MT 2              |
| <b>STYLE 26:</b><br>PIN 1. V <sub>CC</sub><br>2. GROUND 2<br>3. OUTPUT | <b>STYLE 27:</b><br>PIN 1. MT<br>2. SUBSTRATE<br>3. MT                      | <b>STYLE 28:</b><br>PIN 1. CATHODE<br>2. ANODE<br>3. GATE           | <b>STYLE 29:</b><br>PIN 1. NOT CONNECTED<br>2. ANODE<br>3. CATHODE     | <b>STYLE 30:</b><br>PIN 1. DRAIN<br>2. GATE<br>3. SOURCE           |
| <b>STYLE 31:</b><br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE               | <b>STYLE 32:</b><br>PIN 1. BASE<br>2. COLLECTOR<br>3. EMITTER               | <b>STYLE 33:</b><br>PIN 1. RETURN<br>2. INPUT<br>3. OUTPUT          | <b>STYLE 34:</b><br>PIN 1. INPUT<br>2. GROUND<br>3. LOGIC              | <b>STYLE 35:</b><br>PIN 1. GATE<br>2. COLLECTOR<br>3. EMITTER      |

|                         |                              |                                                                                                                                                                                     |
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| <b>DESCRIPTION:</b>     | <b>TO-92 (TO-226) 1 WATT</b> | <b>PAGE 2 OF 2</b>                                                                                                                                                                  |

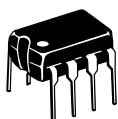
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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

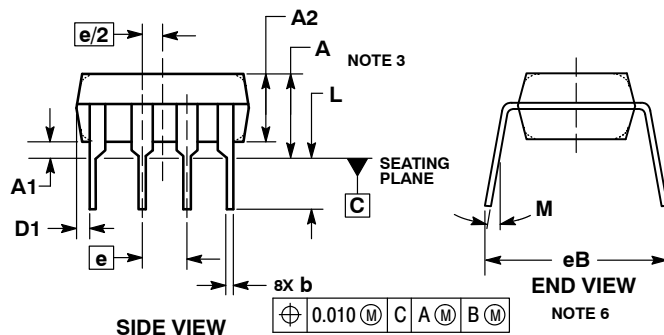
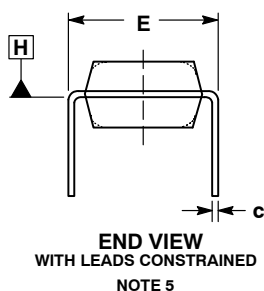
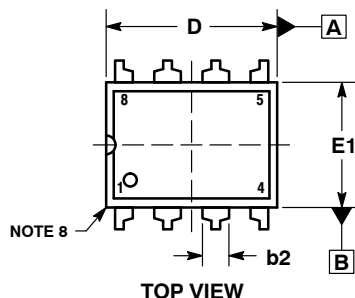
ON Semiconductor®



SCALE 1:1

PDIP-8  
CASE 626-05  
ISSUE P

DATE 22 APR 2015

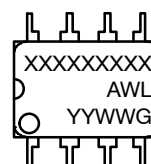


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | ---       | 0.210 | ---         | 5.33  |
| A1  | 0.015     | ---   | 0.38        | ---   |
| A2  | 0.115     | 0.195 | 2.92        | 4.95  |
| b   | 0.014     | 0.022 | 0.35        | 0.56  |
| b2  | 0.060 TYP |       | 1.52 TYP    |       |
| C   | 0.008     | 0.014 | 0.20        | 0.36  |
| D   | 0.355     | 0.400 | 9.02        | 10.16 |
| D1  | 0.005     | ---   | 0.13        | ---   |
| E   | 0.300     | 0.325 | 7.62        | 8.26  |
| E1  | 0.240     | 0.280 | 6.10        | 7.11  |
| e   | 0.100 BSC |       | 2.54 BSC    |       |
| eB  | ---       | 0.430 | ---         | 10.92 |
| L   | 0.115     | 0.150 | 2.92        | 3.81  |
| M   | ---       | 10°   | ---         | 10°   |

### GENERIC MARKING DIAGRAM\*



XXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
YY = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

### STYLE 1:

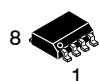
- PIN 1: AC IN  
2. DC + IN  
3. DC - IN  
4. AC IN  
5. GROUND  
6. OUTPUT  
7. AUXILIARY  
8. V<sub>CC</sub>

|                         |                    |                                                                                                                                                                                     |
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| <b>DESCRIPTION:</b>     | <b>PDIP-8</b>      | <b>PAGE 1 OF 1</b>                                                                                                                                                                  |

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

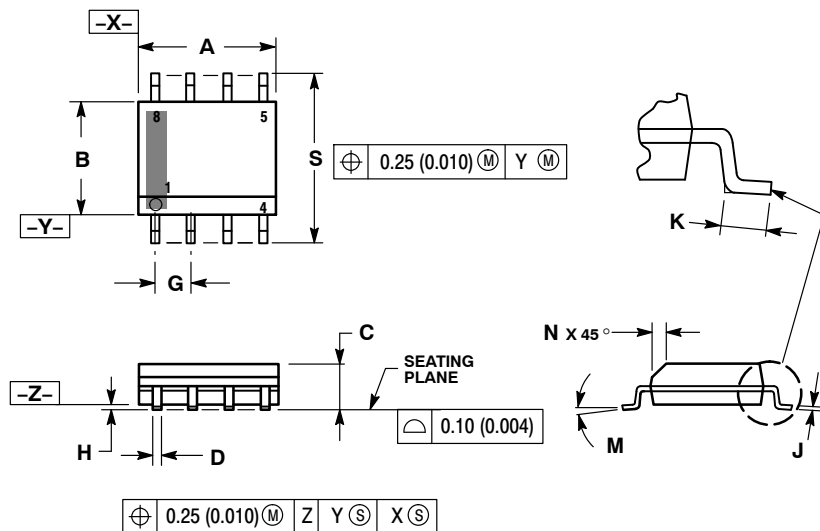
ON Semiconductor®



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

DATE 16 FEB 2011

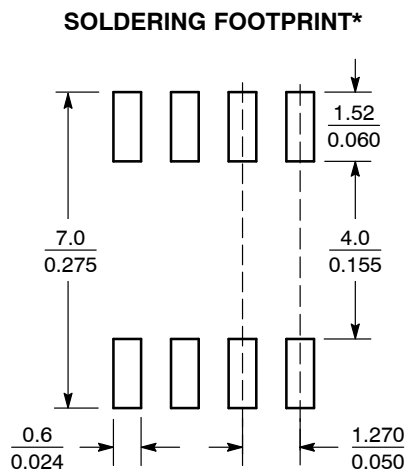


## NOTES:

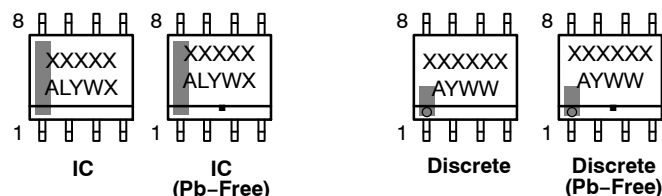
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

## GENERIC MARKING DIAGRAM\*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

|                  |             |                                                                                                                                                                                  |
|------------------|-------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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| DESCRIPTION:     | SOIC-8 NB   | PAGE 1 OF 2                                                                                                                                                                      |

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**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

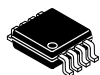
|                                                                                                                                                                                                   |                                                                                                                                                                                          |                                                                                                                                                                                    |                                                                                                                                                                                                        |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER                                                                 | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE                                                                           |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE                                                                               | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE                                                                    | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND                                                              | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1                                               | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                                 |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                              | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN                                                     | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC                                                                                          | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE                                                                 | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1                                             | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6                                        | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT                                                                                         | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC                                                                    | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN                                                            | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN                                                                        |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |                                                                                                                                                                                    |                                                                                                                                                                                                        |

|                         |                    |                                                                                                                                                                                     |
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| <b>DESCRIPTION:</b>     | <b>SOIC-8 NB</b>   | <b>PAGE 2 OF 2</b>                                                                                                                                                                  |

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

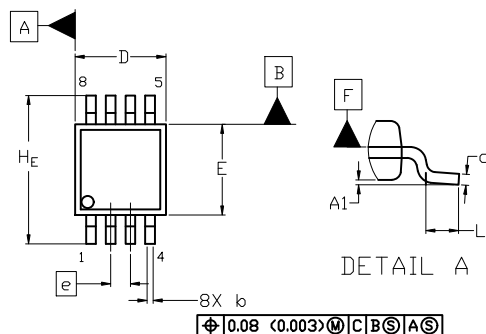
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SCALE 2:1

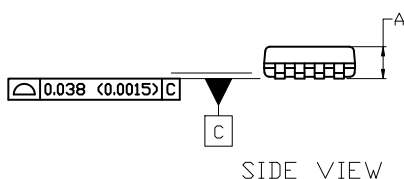
## Micro8 CASE 846A-02 ISSUE K

DATE 16 JUL 2020

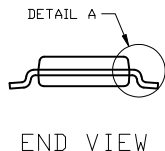


TOP VIEW

NOTE 3



SIDE VIEW



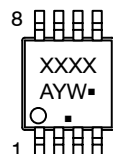
END VIEW

### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION *b* DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS *D* AND *E* DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION *E* DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS *D* AND *E* ARE DETERMINED AT DATUM *F*.
5. DATUMS *A* AND *B* ARE TO BE DETERMINED AT DATUM *F*.
6. *A1* IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

| DIM                  | MILLIMETERS |      |      |
|----------------------|-------------|------|------|
|                      | MIN.        | NOM. | MAX. |
| A                    | ---         | ---  | 1.10 |
| A1                   | 0.05        | 0.08 | 0.15 |
| <i>b</i>             | 0.25        | 0.33 | 0.40 |
| <i>c</i>             | 0.13        | 0.18 | 0.23 |
| <i>D</i>             | 2.90        | 3.00 | 3.10 |
| <i>E</i>             | 2.90        | 3.00 | 3.10 |
| <i>e</i>             | 0.65 BSC    |      |      |
| <i>H<sub>E</sub></i> | 4.75        | 4.90 | 5.05 |
| <i>L</i>             | 0.40        | 0.55 | 0.70 |

### GENERIC MARKING DIAGRAM\*



XXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM-10.

#### STYLE 1:

1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

#### STYLE 2:

1. SOURCE 1
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN 1
8. DRAIN 1

#### STYLE 3:

1. N-SOURCE
2. N-GATE
3. P-SOURCE
4. P-GATE
5. P-DRAIN
6. P-DRAIN
7. N-DRAIN
8. N-DRAIN

|                  |             |                                                                                                                                                                                     |
|------------------|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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